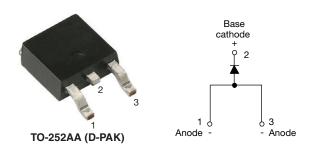


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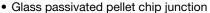
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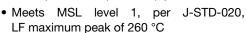
Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



PRODUCT SUMMARY						
Package	TO-252AA (D-PAK)					
I _{F(AV)}	8 A					
V _R	1000 V, 1200 V					
V _F at I _F	1.3 V					
I _{FSM}	150 A					
t _{rr}	80 ns					
T _J max.	150 °C					
Diode variation	Single die					
Snap factor	0.6					

FEATURES







 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT

APPLICATIONS

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

DESCRIPTION

The VS-8EWF..S-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Sinusoidal waveform	8	Α					
V _{RRM}		1000/1200	V					
I _{FSM}		150	Α					
V _F	8 A, T _J = 25 °C	1.3	V					
t _{rr}	1 A, 100 A/µs	80	ns					
TJ	Range	-40 to +150	°C					

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA					
VS-8EWF10SPbF	1000	1100	4					
VS-8EWF12SPbF	1200	1300	4					

ABSOLUTE MAXIMUM RATINGS							
PARAMETER SYMBOL TEST CONDITIONS VALUES							
Maximum average forward current	I _{F(AV)}	T _C = 94 °C, 180° conduction half sine wave	8				
Maximum peak one cycle non-repetitive surge current	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	125	Α			
		10 ms sine pulse, no voltage reapplied	150				
12. 5 . 5 .	I ² t	10 ms sine pulse, rated V _{RRM} applied	78	A ² s			
Maximum I ² t for fusing		10 ms sine pulse, no voltage reapplied	110	A-S			
Maximum I²√t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied	1100	A²√s			



VS-8EWF..SPbF Soft Recovery Series

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ELECTRICAL SPECIFICATIONS							
PARAMETER	VALUES	UNITS					
Maximum forward voltage drop	V_{FM}	8 A, T _J = 25 °C	1.3	V			
Forward slope resistance	r _t	T - 150 °C	25.6	mΩ			
Threshold voltage	V _{F(TO)}	1j = 150 C	T _J = 150 °C				
Maximum reverse leakage current	1	T _J = 25 °C	V _B = Rated V _{BBM}	0.1	mΛ		
Maximum reverse leakage current	IRM	T _J = 150 °C	VR = naleu VRRM	4	mA mA		

RECOVERY CHARACTERISTICS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •			
Reverse recovery time	t _{rr}	I _F at 8 A _{pk} 25 Α/μs Τ _J = 25 °C	270	ns	I _{FM} t			
Reverse recovery current	I _{rr}		4.2	Α	$t_a \mid t_b$			
Reverse recovery charge	Q _{rr}		1	μC	di / Q _{rr}			
Snap factor	S		0.6		V Im			

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W			
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		50				
Approximate weight			1	g			
Approximate weight			0.03	OZ.			
Marking device		Case style TO-252AA (D-PAK)	8EWF12S				

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

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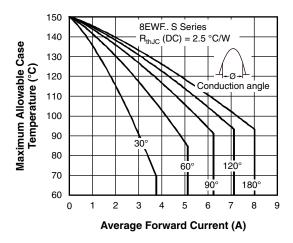


Fig. 1 - Current Rating Characteristics

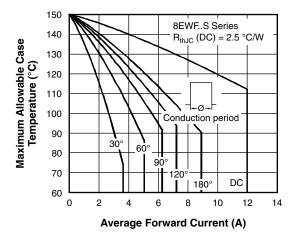


Fig. 2 - Current Rating Characteristics

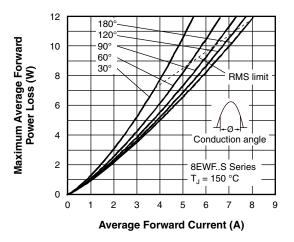


Fig. 3 - Forward Power Loss Characteristics

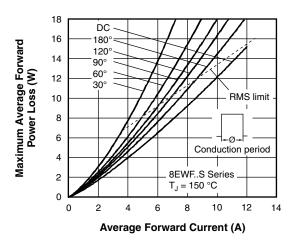


Fig. 4 - Forward Power Loss Characteristics

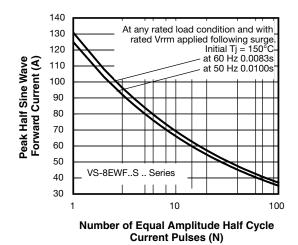


Fig. 5 - Maximum Non-Repetitive Surge Current

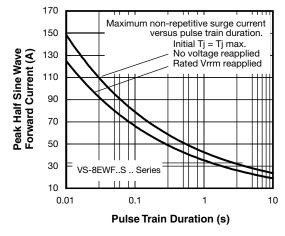


Fig. 6 - Maximum Non-Repetitive Surge Current

8EWF.S Series

T_J = 25 °C

2.0

1.6

1.2

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I_{FM} = 10 A

 $I_{FM} = 8 A$

I_{FM} = 2 A

200

160

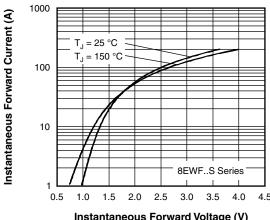
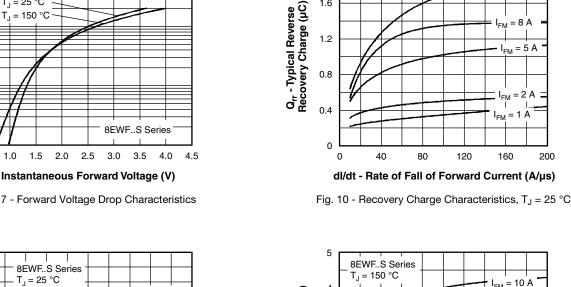


Fig. 7 - Forward Voltage Drop Characteristics



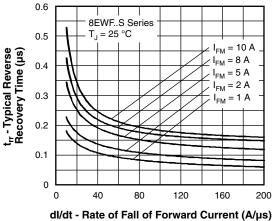
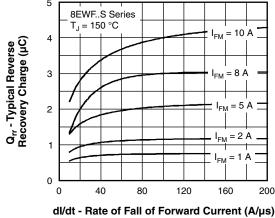


Fig. 8 - Recovery Time Characteristics, $T_J = 25$ °C



80

120

Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

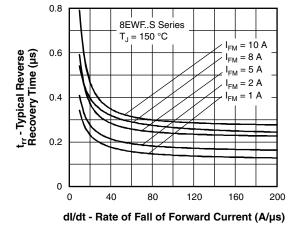


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

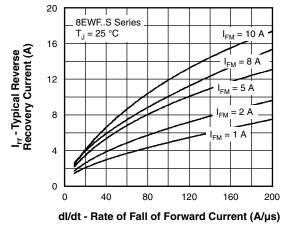


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

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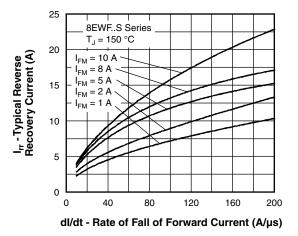


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

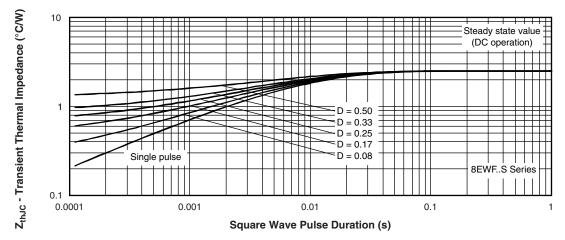


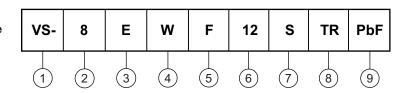
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

VS-8EWF..SPbF Soft Recovery Series

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

3 - Circuit configuration:

E = single diode

4 - Package:

W = D-PAK

5 - Type of silicon:

F = fast soft recovery rectifier

- Voltage code x 100 = V_{RRM} —

10 = 1000 V 12 = 1200 V

7 - S = surface mountable

TR = tape and reel

• TRR = tape and reel (right oriented)

• TRL = tape and reel (left oriented)

9 - None = standard production

• PbF = lead (Pb)-free

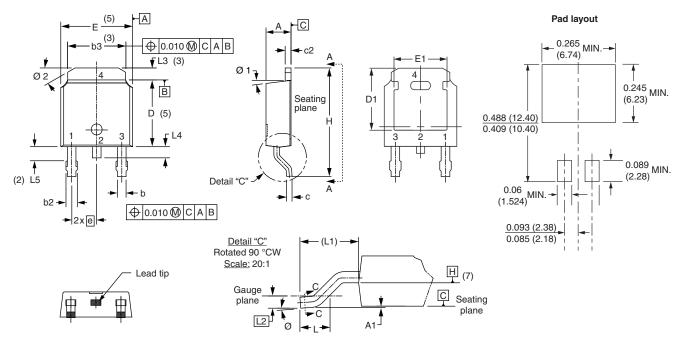
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95016</u>						
Part marking information	www.vishay.com/doc?95059					
Packaging information	www.vishay.com/doc?95033					
SPICE model	www.vishay.com/doc?95552					



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D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES		SYMBOL	ı
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STINIBUL	N
Α	2.18	2.39	0.086	0.094			е	
A1	-	0.13	-	0.005			Н	Ś
b	0.64	0.89	0.025	0.035			L	•
b2	0.76	1.14	0.030	0.045			L1	
b3	4.95	5.46	0.195	0.215	3		L2	
С	0.46	0.61	0.018	0.024			L3	(
c2	0.46	0.89	0.018	0.035			L4	
D	5.97	6.22	0.235	0.245	5		L5	,
D1	5.21	-	0.205	-	3		Ø	
E	6.35	6.73	0.250	0.265	5		Ø1	
E1	4.32	-	0.170	-	3		Ø2	

SYMBOL	MILLIN	MILLIMETERS		HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	BSC	0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA

Revision: 05-Dec-12 1 Document Number: 95016

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